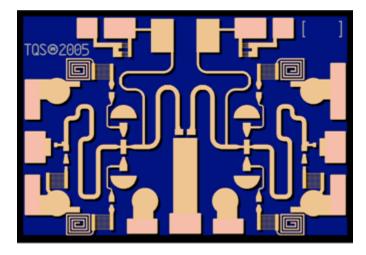


High Power Ka-Band Absorptive SPDT Switch TGS4304



Description

The TriQuint TGS4304 is a GaAs absorptive single-pole, double-throw (SPDT) PIN monolithic switch designed to operate over the Ka-Band frequency range. This switch maintains a low insertion loss with high power handling of 33dBm or greater input P1dB at V_c = +10V. These advantages, along with the small size of the chip, make the TGS4304 ideal for use in communication and transmit/receive applications.

The TGS4304 is 100% DC & RF tested on-wafer to ensure performance compliance.

Lead free and RoHS compliant.

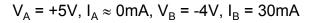
Key Features and Performance

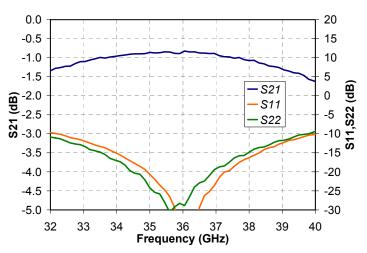
- 32 40 GHz Frequency Range
- > 33 dBm Input P1dB @ V_c = +10V
- On Chip Biasing Resistors
- On Chip DC Blocks
- < 1.0 dB Midband Insertion Loss
- < 4ns Switching Speed
- VPIN Technology
- Chip Dimensions:
 1.58 x 1.10 x 0.10 mm
 (0.043 x 0.062 x 0.004 inches)

Primary Applications

- Ka-Band Transmit / Receive
- Point-to-Point Radio
- Point-to-Multipoint Radio

Measured Data





Note: This device is early in the characterization process prior to finalizing all electrical test specifications. Specifications are subject to change without notice.

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TABLE I MAXIMUM RATINGS

Symbol	Parameter 1/	Value	Notes
Vc	Control Voltage	-5V to +25V	2/
Ι _C	Control Current	34 mA	<u>2/</u>
P _{IN}	Input Continuous Wave Power	35 dBm	
T _M	Mounting Temperature (30 Seconds)	320 ⁰ C	
T _{STG}	Storage Temperature	-65 to 150 ⁰ C	

<u>1</u>/ These ratings represent the maximum operable values for this device.

- $\underline{2}$ / V_C and I_C are per bias pad.
- 3/ Operation above 30dBm requires control voltages above +7.5V.

TABLE IIRF CHARACTERIZATION TABLE $(T_A = 25^{\circ}C, Nominal)$ $(V_A = +5V, I_A = 0mA, V_B = -4V, I_B = 30mA)$

Symbol	Parameter	Test Conditions	Тур	Units	Notes
IL	Insertion Loss	F = 32 – 34 GHz F = 34 – 37 GHz F = 37 – 40 GHz	1.3 0.9 1.3	dB	
RL	Return Loss	F = 32 – 40 GHz	10	dB	
P1dB	Output Power @ 1dB Gain Compression	$V_{C} = +5 V$ $V_{C} = +7.5 V$ $V_{C} = +10 V$ $V_{C} = +20 V$	31 33 34 34.5	dBm	<u>1</u> /

Note: Table II Lists the RF Characteristics of typical devices as determined by fixtured measurements.

1/ Frequency = 30GHz

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Selected RF Output	V _A	V _B
RF Out A	≥ +5V @ ~0mA	-4V @ 30mA
RF Out B	-4V @ 30mA	≥ +5V @ ~0mA

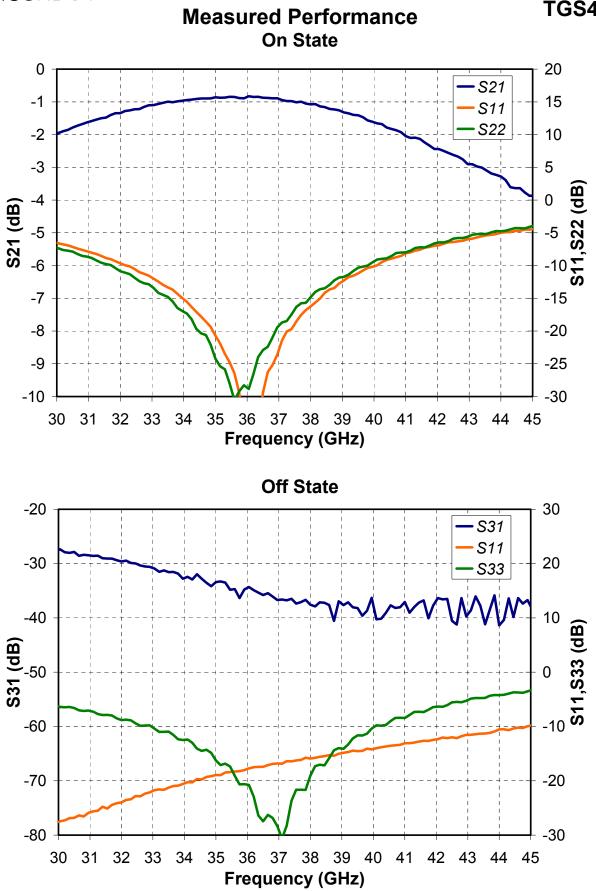
TABLE III TRUTH TABLE

Selected RF Output	۱ _A	Ι _Β
RF Out A	≥ +5V @ ~0mA	30mA
RF Out B	30mA	≥ +5V @ ~0mA

Operation at RF power levels >30 dBm requires increasing the positive voltage level to put a larger reverse bias on the diodes while the negative voltage level remains at -4V with a current of approximately 30mA. If you are using -5V, use alternate assembly with off chip resistors.

Bond pads IA and IB bypass the on-chip series resistors to allow adjustment of the current to the diodes in their forward biased state.



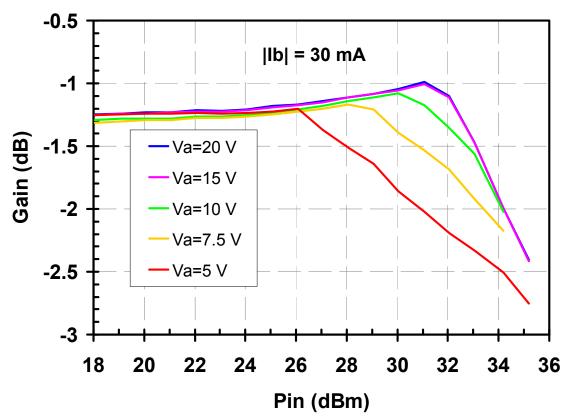


TGS4304

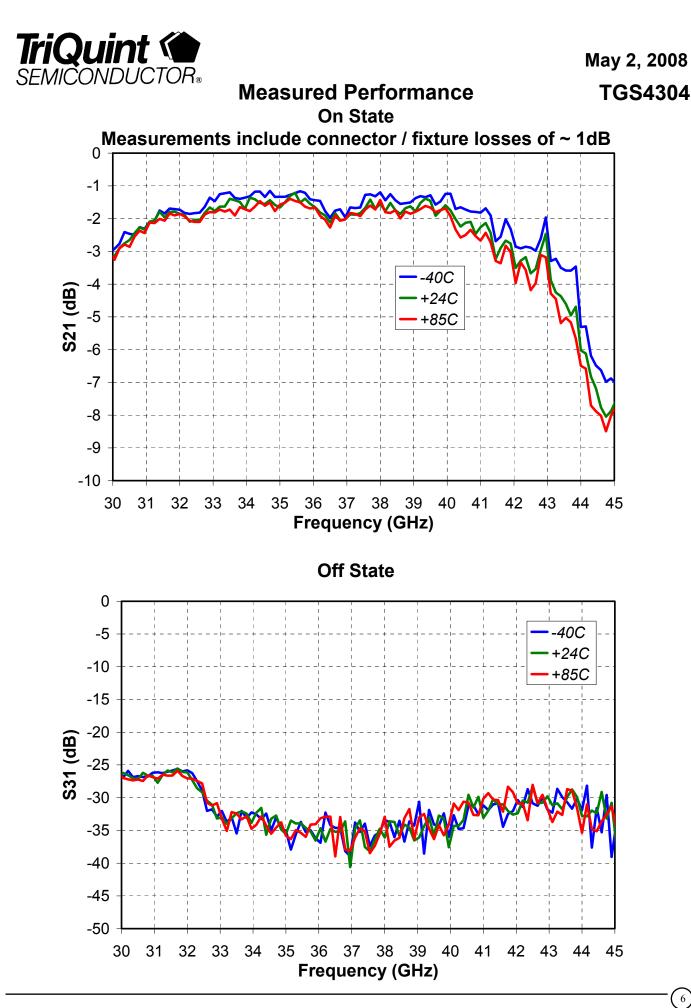
4







(5)



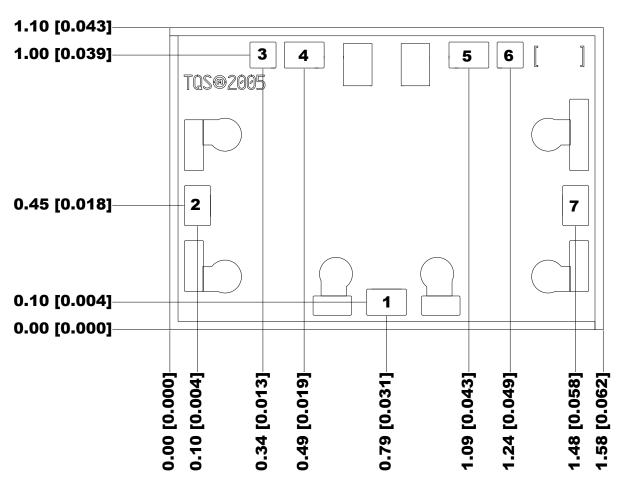
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7

Mechanical Drawing



Units: millimeters (inches) Thickness: 0.100 (0.004) Chip edge to bond pad dimensions are shown to center of bond pad Chip size tolerance: +/- 0.051 (0.002)

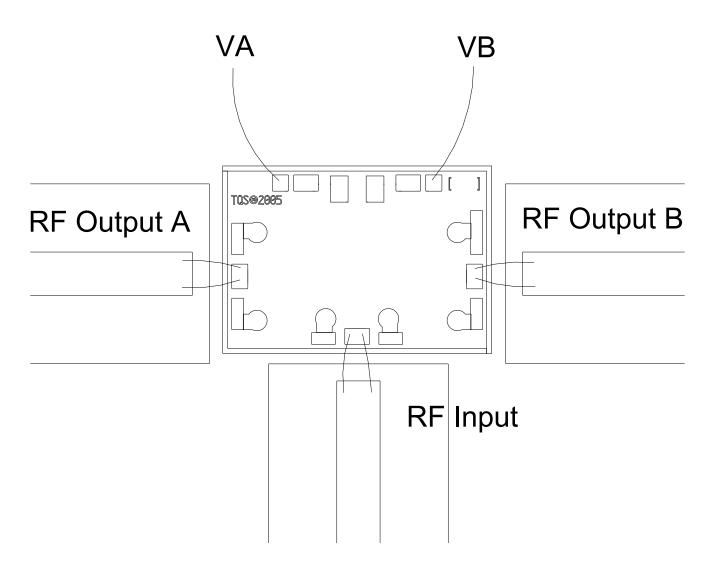
GND IS BACKSIDE OF MMIC

Bond Pad #1	(RF In)	0.15 x 0.10 (0.006 x 0.004)
Bond Pad #2	(RF Out A)	0.10 x 0.15 (0.004 x 0.006)
Bond Pad #3	(VA)	0.10 x 0.10 (0.004 x 0.004)
Bond Pad #4	(IA)	0.15 x 0.10 (0.006 x 0.004)
Bond Pad #5	(IB)	0.15 x 0.10 (0.006 x 0.004)
Bond Pad #6	(VB)	0.10 x 0.10 (0.004 x 0.004)
Bond Pad #7	(RF Out B)	0.10 x 0.15 (0.004 x 0.006)



Chip Assembly & Bonding Diagram



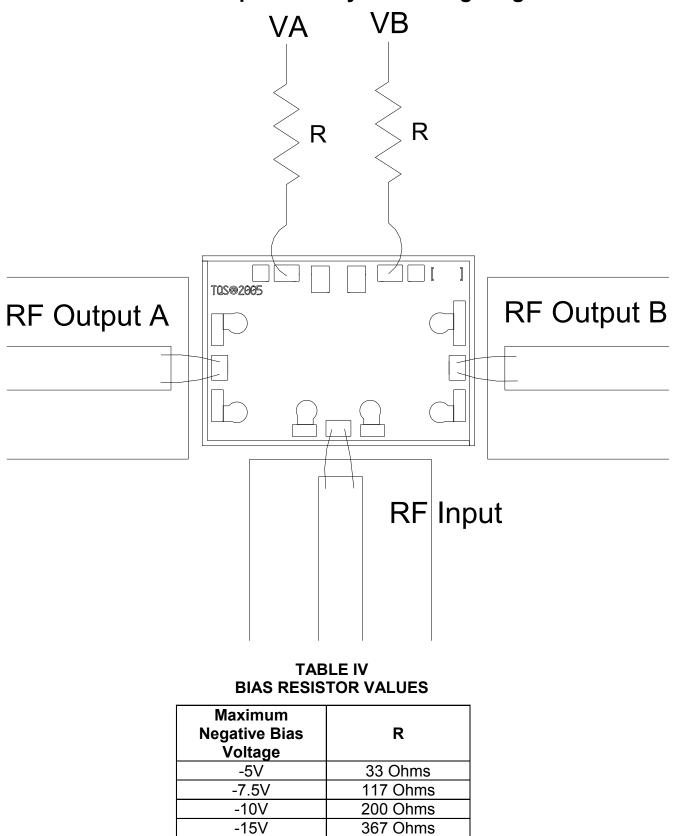


GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.



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Alternate Chip Assembly & Bonding Diagram TGS4304



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533 Ohms

-20V

(9)



Assembly Process Notes

Reflow process assembly notes:

- Use AuSn (80/20) solder with limited exposure to temperatures at or above 300°C. (30 seconds maximum)
- An alloy station or conveyor furnace with reducing atmosphere should be used.
- No fluxes should be utilized.
- Coefficient of thermal expansion matching is critical for long-term reliability.
- Devices must be stored in a dry nitrogen atmosphere.

Component placement and adhesive attachment assembly notes:

- Vacuum pencils and/or vacuum collets are the preferred method of pick up.
- Air bridges must be avoided during placement.
- The force impact is critical during auto placement.
- Organic attachment can be used in low-power applications.
- Curing should be done in a convection oven; proper exhaust is a safety concern.
- Microwave or radiant curing should not be used because of differential heating.
- Coefficient of thermal expansion matching is critical.

Interconnect process assembly notes:

- Thermosonic ball bonding is the preferred interconnect technique.
- Force, time, and ultrasonics are critical parameters.
- Aluminum wire should not be used.
- Maximum stage temperature is 200°C.

GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.

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 MASW-002102-13580G
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